

Analysis of deep level centers in GaAs pin-diode structures

Korolkov, Oleg; Toompuu, Jana; Rang, Toomas Elektronika ir elektrotehnika = Electronics and electrical engineering 2013 / [4 p.] : ill

Investigation of deep level centers in i- and n-layers of GaAs pin-diodes

Toompuu, Jana; Korolkov, Oleg; Sleptšuk, Natalja; Rang, Toomas BEC 2014 : 2014 14th Biennial Baltic Electronics Conference : proceedings of the 14th Biennial Baltic Electronics Conference : Tallinn University of Technology, October 6-8, 2014, Tallinn, Estonia 2014 / p. 25-28 : ill

Method of samples preparation intended for research of deep centers in i-, n-, and p-layers of GaAs p⁺-pin-n⁺ structures and result of analysis

Toompuu, Jana; Sleptšuk, Natalja; Korolkov, Oleg; Rang, Toomas BEC 2016 : 2016 15th Biennial Baltic Electronics Conference : proceedings of the 15th Biennial Baltic Electronics Conference : Tallinn University of Technology, October 3-5, 2016, Tallinn, Estonia 2016 / p. 35-38 : ill http://www.estee.ee/record=b2150914*est

Spectral properties of incoherent terahertz torch based on parabolic Ga(As,Bi)/AlGaAs quantum wells

Karaliunas, Mindaugas; Pagalys, Justas; Jakštė, Vytautas; Norkus, Ričardas; Urbanowicz, Andrzej; Devenson, Jan; Devenson, Renata; **Udal, Andres**; Valušis, Gintaras Terahertz Emitters, Receivers, and Applications X : SPIE Optical Engineering + Applications, 11-15 August 2019, San Diego, California, United States : proceedings SPIE digital library 2019
<https://doi.org/10.1117/12.2528428> Conference proceeding at Scopus Article at Scopus Article at WOS